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Attorney Docket No.

Patent 015290-458

### THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent of

Christopher C. Chang et al.

Patent No.:

6,805,952 82

Issued:

October 19, 2004

Title:

LOW CONTAMINATION PLASMA CHAMBER COMPONENTS AND METHODS FOR MAKING THE

SAME

#### REQUEST FOR CERTIFICATE OF CORRECTION

Certificate
NOV 2 3 2004
of Correction

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Issuance of a Certificate of Correction for the above-captioned patent is respectfully requested in accordance with the accompanying Form PTO-1050 (submitted in duplicate).

	The requisite Government fee of \$100.00 (1811)			
		Is submitted herewi	th.	
	☐ Is authorized to be charged to Deposit Account No. 02-4800.			
		Charge	to credit card. Form PTO-2038 is attached.	
×	It is	believed that payme	ent of a fee is unnecessary.	
Со	lumr	n 10, line 16, Claim 1	6 is incomplete as noted on the attached Form 1050.	

The Director is hereby authorized to charge any appropriate fees under 37 C.F.R. § 1.20(a) that may be required by this paper, and to credit any overpayment, to Deposit Account No. 02-4800. This paper is submitted in duplicate.

Respectfully submitted,

BURNS, DOANE, SWECKER & MATHIS, L.L.P.

P.O. Box 1404 Alexandria, Virginia 22313-1404 (703) 836-6620

Date: November 19, 2004

Ву

Peter K. Skiff

Registration No. 31,917



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## UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO. : 6,805,952 \$2.

DATED : October 19, 2004

INVENTOR(S) : Christopher C. Chang et al.

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

In column 10, line 16 of the patent, "16. The component of claim 15, wherein the coating is." should read as follows:

--16. A component of a plasma etch reactor, the component comprising aluminum having an anodized or non-anodized plasma exposed surface, the component comprising an as-sprayed plasma sprayed coating on a plasma exposed surface of the component, the coating being a ceramic material selected from the group consisting of alumina, yttria, zirconia, silicon carbide, silicon nitride, boron carbide and boron nitride, and the coating having an as-sprayed surface roughness that promotes the adhesion of polymer deposits formed during etching of semiconductor substrates in the plasma etch reactor.--

MAILING ADDRESS OF SENDER:

PATENT NO. 6,805,952

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# UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO.

6,805,952 BZ

DATED

October 19, 2004

INVENTOR(S)

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